



TRADCARE: tool for SEE prediction in a radiation environment

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Context

- Study started in 2012
- Most of the SEE rate estimation tools limited to RPP methods:
 - Not considering shielding surrounding the sensitive area,
 - Charge deposition based on mean LET

• Need to create a prediction tool using Monte Carlo capabilities:

- Considering the shielding/materials around the sensitive area,
- Charge deposition based on deposited energy through realistic particle interactions
- Others characteristics:
 - Generalist regarding the IC type and the SEE type to predict,
 - Allowing to study isotropic environments (SEE rate prediction) and also irradiation beams (cross section analysis)

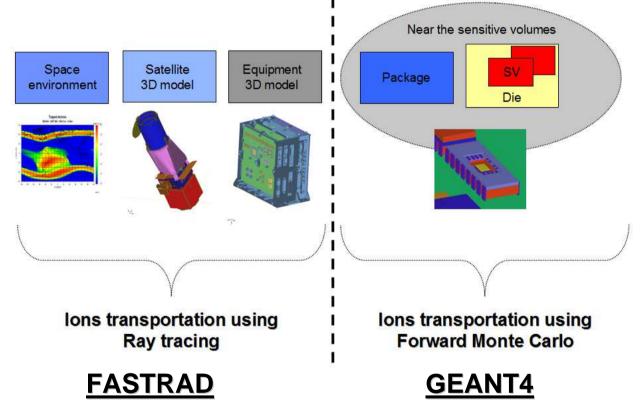




First generation

2012 - 2013 :

SEE rate estimation tool taking into account physical interaction processes and shielding



Deposited charges in the sensitive volumes are calculated

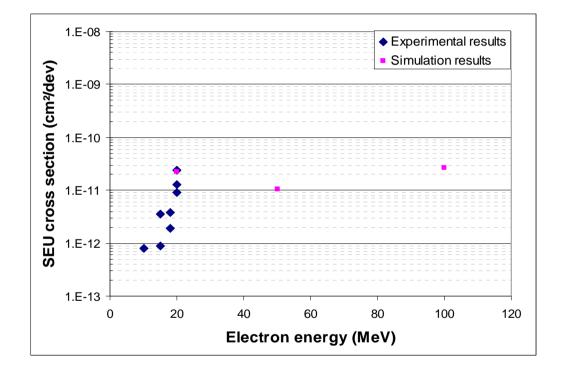
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E.g. Cross section simulation vs tests (electrons)



Calculation parameters (critical charge, sensitive volume thickness and area) were defined using test data

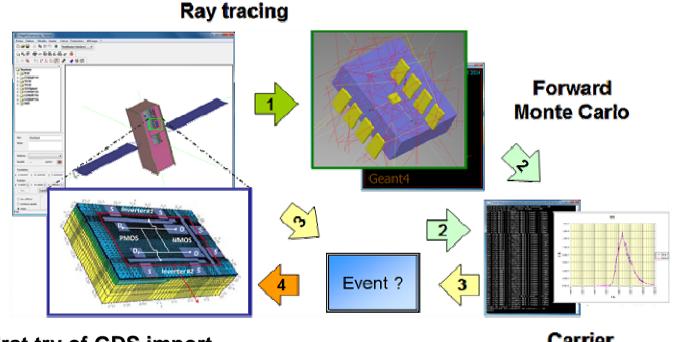


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Second generation

2014 :



2nd generation of the SEE rate estimation tool

First try of GDS import

Carrier transportation

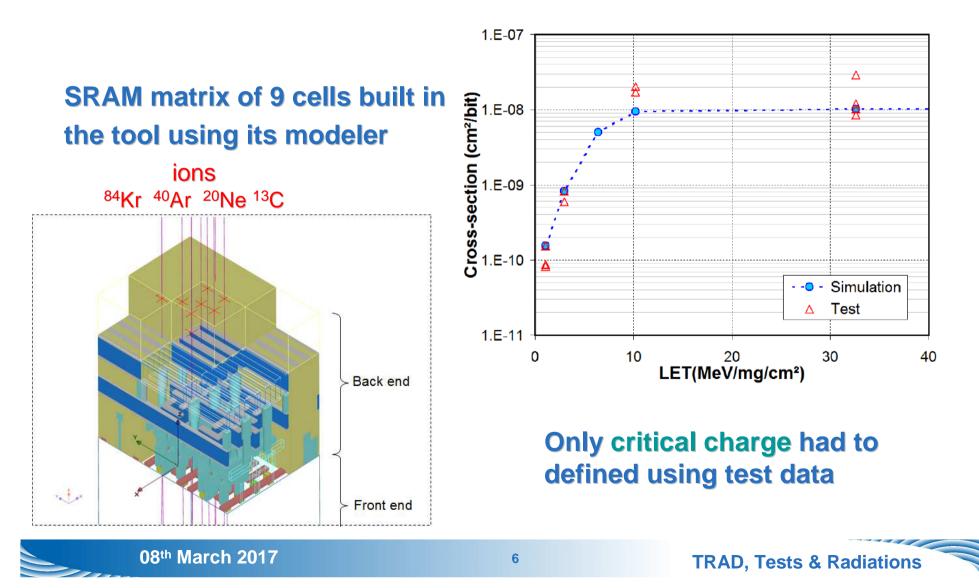
Carrier transportation models were introduced to take into account the carrier diffusion to collection area through substrate







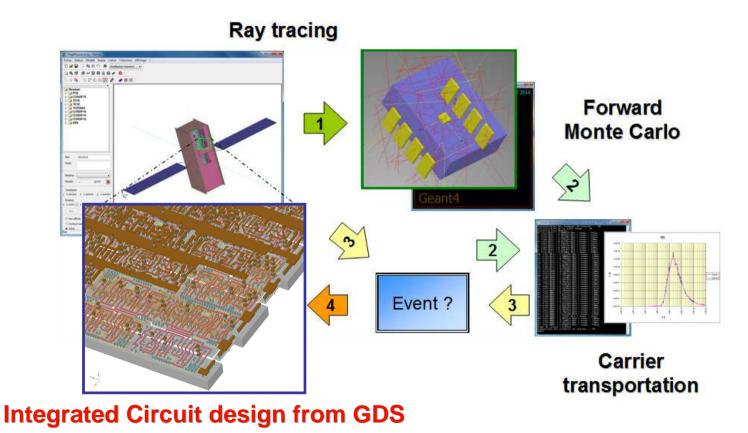
E.g. Cross section simulation VS test (cocktail of ions)





2015 - 2017 :

Several enhancements based on GDS, TCAD, and SPICE

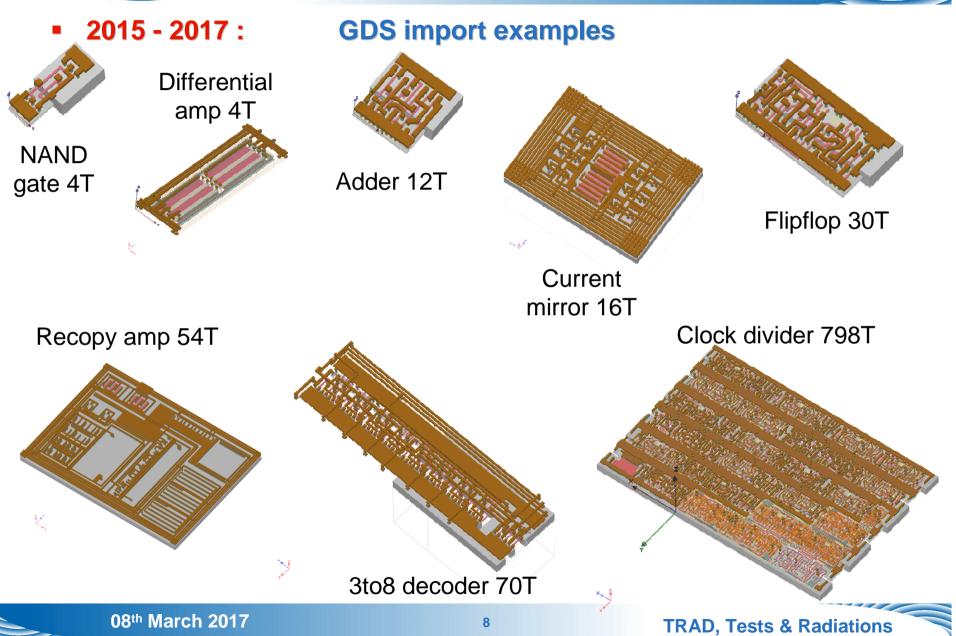


From now on, the IC model can be automatically built



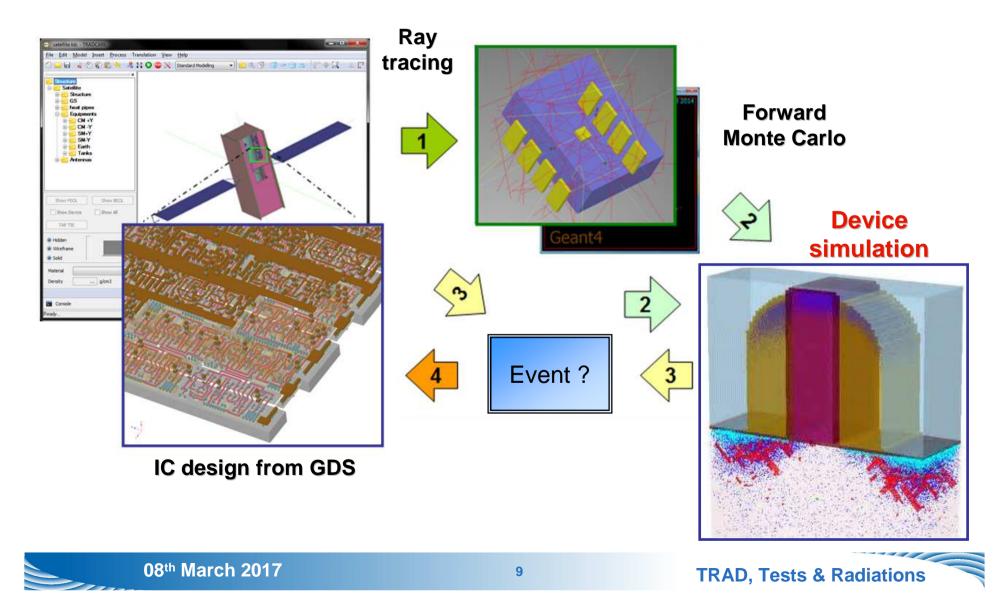
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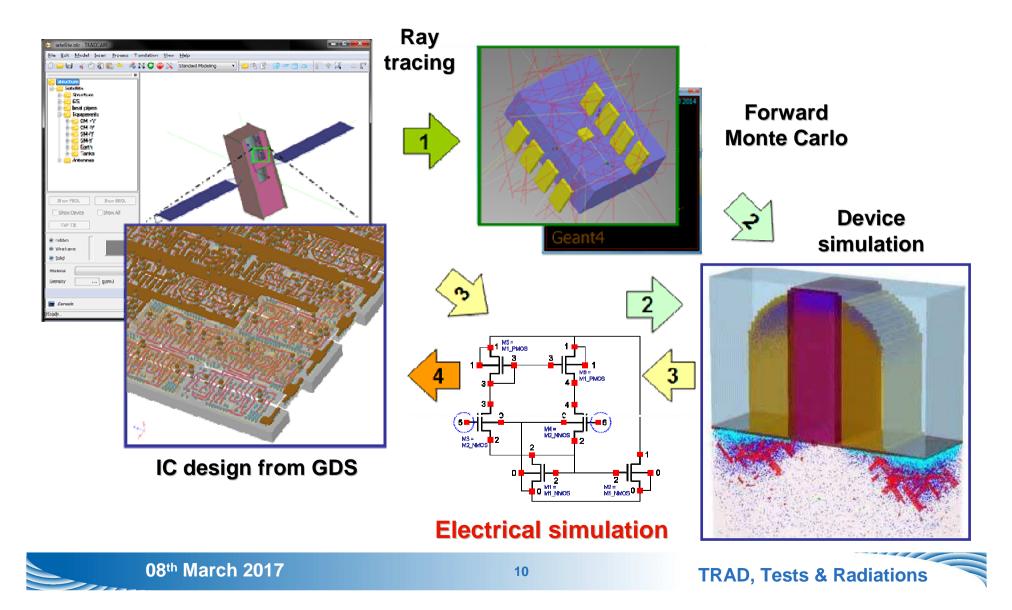


Carrier transportation based on device simulation (TCAD tool)



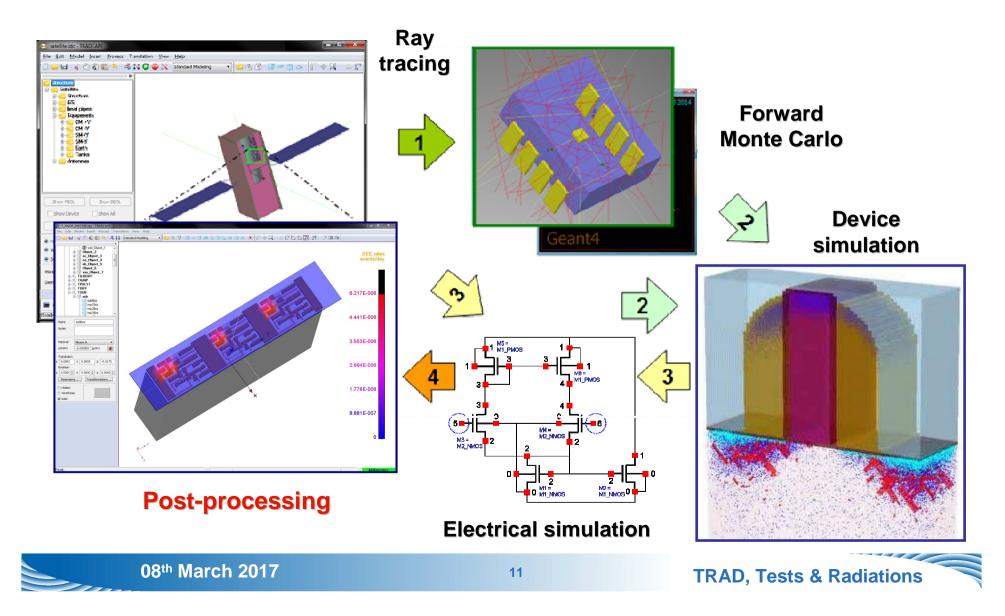


Event detection based on electrical simulation (SPICE-like tool)





Graphical representation of the IC sensitivity







Prototype in a validation phase

Including:

- IC model from GDS
- Ions transportation based on Ray Tracing and Forward Monte Carlo
- Carrier transportation based on device simulation (TCAD tool)
- Event detection based on electrical simulation (SPICE-like tool),
- IC sensitivity mapping

Generalist tool

- Predictions possible for different types of SEE : SEU/MBU, SET, SEL
- Prediction method not specific to a certain IC technology
- On-going validation with CMOS technology
- Open to expand the validation to other technologies







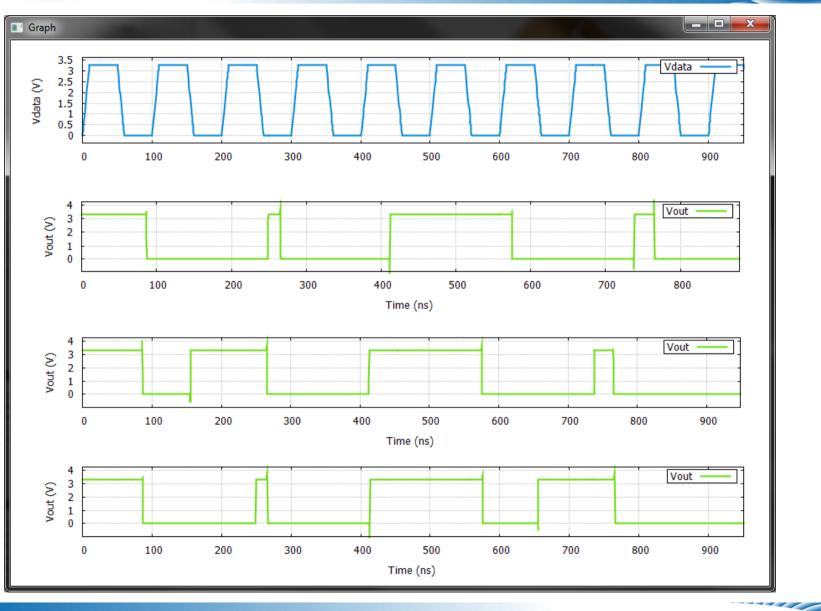
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Event detection



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TRAD, Tests & Radiations



Actual version

From system to circuit

 \rightarrow Taking into account the satellite shielding

